

PCN# 20220817001.1 Qualification of new Fab site (FFAB) using qualified Process Technology, Die Revision, Datasheet update and additional Assembly site/BOM options for select devices Change Notification / Sample Request

Date:August 18, 2022To:TOKYO ELECTRON DEVICE (DSTR) PCN

Dear Customer:

This is an announcement of a change to a device that is currently offered by Texas Instruments (TI). The details of this change are on the following pages, and are in alignment with our standard product change notification (PCN) <u>process</u>.

TI requires acknowledgement of receipt of this notification within 30 days of the date of this notice. Lack of acknowledgement of this notice within 30 days constitutes acceptance of the change. If samples or additional data are required, requests must be received within 30 days of this notification, given that samples are not built ahead of the change.

The Proposed First Ship date in this PCN letter is the earliest possible date that customers could receive the changed material. It is our commitment that the changed device will not ship before that date. If samples are requested within the 30 day sample request window, customers will still have 30-days to complete their evaluation regardless of the proposed 1st ship date.

This particular PCN is related to TI's multiyear transition plan for our two remaining factories with 150-millimeter production (DFAB in Dallas, Texas, and SFAB in Sherman, Texas). DFAB will remain open, but will focus on 200-mm production, with a smaller set of technologies. SFAB will close no earlier than 2024 and no later than 2025. As referenced in the "reason for change" below, these changes are part of our multiyear plan to transition these products to newer, more efficient manufacturing processes and technologies, underscoring our commitment to product longevity and supply continuity.

For questions regarding this notice or to provide acknowledgement of this PCN, you may contact your local Field Sales Representative or the PCN Team (<u>PCN ww admin team@list.ti.com</u>). For sample requests or sample related questions, contact your local Field Sales Representative. As always, we thank you for your continued business.

PCN Team SC Business Services

20220817001.1 Attachment: 1

Products Affected:

The devices listed on this page are a subset of the complete list of affected devices. According to our records, these are the devices that you have purchased within the past twenty-four (24) months. The corresponding customer part number is also listed, if available.

DEVICE

THS4130CDGK

CUSTOMER PART NUMBER

null

Technical details of this Product Change follow on the next page(s).

PCI	N Number:			220817001.1			N Date:	August 18, 2022	
Title: Qualification of new				v Fab site (FFAB) using qualified Process Technology, Die Revision,					
T ICI	Datasheet	update	e and	additional Assembly	site for sele	ect de	evices		
Cus	stomer Contact:		PCN N	<u>Manager</u>	Dept:		Qua	ality Services	
Proposed 1 st Ship Date:			Nov 18, 2022		Sample requests accepted until:			Sep 18, 2022*	
*Sa	mple requests re	ceive	d afte	er September 18, 2	2022 will n	ot be	e support	ted.	
Cha	ange Type:								
\boxtimes	Assembly Site			Assembly Process		\boxtimes	Assembly Materials		
\boxtimes	Design		\square	Electrical Specifica	tion		Mechanical Specification		
	Test Site		\square	Packing/Shipping/	Labeling		Test Process		
Wafer Bump Site			Wafer Bump Material			Wafer Bump Process			
\boxtimes	Wafer Fab Site			Wafer Fab Materia	ls	\square	Wafer Fa	ab Process	
				Part number change					
				DCN Data	1				

PCN Details

Description of Change:

Texas Instruments is pleased to announce the qualification of a new fab & process technology (FFAB, BICOMHD) and additional Assembly site (HFTF) for selected devices as listed below in the product affected section.

C	urrent Fab Site	3	Additional Fab Site			
Current Fab Site	Process	Wafer Diameter	Additional Fab Site	Process	Wafer Diameter	
DL-LIN	BICOM	150 mm	FFAB	BICOMHD	200 mm	

The die was also changed as a result of the process change.

Construction differences are noted below:

	HANA	HFTF
Mount compound	400154	A-18
Mold Compound	450179	R-30
Wire type	1.0 mil Au	1.0 mil Cu
Lead finish	Non-roughened NiPdAu	Roughened NiPdAu

The datasheet will be changing as a result of the above mentioned changes. The datasheet change details can be reviewed in the datasheet revision history. The link to the revised datasheet is available in the table below.



THS4130, THS4131

Page

SLOS318K - MAY 2000 - REVISED AUGUST 2022

Changes from Revision J (March 2022) to Revision K (August 2022)

- Changed title of Electrical Characteristics: THS413xDGK, THS413xDGN table to Electrical Characteristics: THS413xDGN
 9
- Changed title of Typical Characteristics: THS413xD to Typical Characteristics: THS413xD, THS413xDGK .. 11

Product Family	Current Datasheet Number	New Datasheet Number	Link to full datasheet
THS413x	SLOS 318J	SLOS318K	https://www.ti.com/product/THS4130

Tube versions of the devices are included in EOL notice PDN# 20220817002.3

Qual details are provided in the Qual Data Section.

Reason for Change:

These changes are part of our multiyear plan to transition products from our 150-milimeter factories to newer, more efficient manufacturing processes and technologies, underscoring our commitment to product longevity and supply continuity.

Anticipated impact on Form, Fit, Function, Quality or Reliability (positive / negative): None

Impact on Environmental Ratings

Checked boxes indicate the status of environmental ratings following implementation of this change. If below boxes are checked, there are no changes to the associated environmental ratings.

RoHS	REACH	Green Status	IEC 62474
🛛 No Change	🛛 No Change	🛛 No Change	🛛 No Change

Changes to product identification resulting from this PCN:

Fab Site Information:

Chip Site	Chip Site Origin Code (20L)	Chip Site Country Code (21L)	Chip Site City
DL-LIN	DLN	USA	Dallas
FR-BIP-1	TID	DEU	Freising

Die Rev:

Current	New
Die Rev [2P]	Die Rev [2P]
А	Α

Assembly Site Information:

Assembly Site	Assembly Site Origin (22L)	Assembly Country Code (23L)	Assembly City
Hana Semiconductor	HNT	THA	Ayutthaya
Hefei Tongfu Microelectronics Co. Ltd.	HFT	CHN	Hefei

Sample product shipping label (not actual product label)

TEXAS INSTRUMENTS MADE IN: Malaysia 2DC: 20: MSL '2 /260C/1 YEAR SEAL MSL 1 /235C/UNLIM 03/29 0PT: ITEM: 39 LBL: 5A (L)T0:175	оч рт /04 1462-15 147-16 1462-15 1462-15 147-15 1462-15 147-	(1P) SN74LS07NSR (Q) 2000 (D) 0336 (31T) LOT: 3959047MLA (4W) TKY(1T) 75234835 (P) (2P) REV: (V) 00333 (20L) COOLER (21L) CCOLE (22L) ASO: MLA (23L) ACO: M	512 17			
Product Affected:						
Group 1 Device list (Wafer fab, die revision, Assembly site/BOM and Datasheet)						
THS4130IDGKR	THS4131CDGKR	THS4131IDGKR				
			_			

Group 2 Device list (Datasheet changes only)				
THS4130CDGK	THS4131CDGK	THS4131IDGK		
THS4130IDGK	THS4131CDGKG4	THS4131IDGKG4		

For alternate parts with similar or improved performance, please visit the product page on TI.com

Qualification Report

Approve Date 11-May-2022

Qualification Results

Data Displayed as: Number of lots / Total sample size / Total failed

Туре	Test Name / Condition	Duration	Qual Device: <u>THS4130DGK</u>	QBS Product Reference: <u>THS4130ID</u>	QBS Process Reference: <u>OPA2810IDGK</u>	QBS Package Reference: <u>OPA2607QDGKRQ1</u>	QBS Package Reference: <u>OPA2991QDGKRQ1</u>
HTOL	Life Test, 125C	1000 Hours	-	-	3/231/0	-	-
HTOL	Life Test, 150C	408 Hours	-	-	-	1/77/0	3/231/1 (1)
ELFR	Early Life Failure Rate, 125C	48 Hours	-	-	3/3000/0	-	-
нвм	ESD - HBM	2500 V	-	1/3/0	3/9/0	1/3/0	-
CDM	ESD - CDM	1000 V	1/3/0	1/3/0	3/9/0	1/3/0	-
CDM	ESD - CDM	1500 V	1/3/0	1/3/0	3/9/0	1/3/0	-
LU	Latch-up	Per JESD78	-	1/6/0	3/18/0	-	-
ED	Electrical Characterization	Per Datasheet Parameters	-	1/30/0	3/90/0	-	-
AC	Autoclave 121C	96 Hours	-	-	-	-	3/231/0
HAST	Biased HAST, 130C/85%RH	96 Hours	-	-	3/231/0	1/77/0	3/231/2 (1)
HTSL	High Temp Storage Bake 150C	1000 Hours	-	-	-	1/77/0	2/90/0
HTSL	High Temp Storage Bake 170C	420 Hours	-	-	3/231/0	-	-
UHAST	Unbiased HAST 130C/85%RH	96 Hours	1/77/0	-	3/231/0	1/77/0	-
тс	Temperature Cycle, - 65/150C	500 Cycles	1/77/0	-	3/231/0	-	3/231/1
LI	Lead Pull	Lead Pull	-	-	-	1/6/0	-

Туре	Test Name / Condition	Duration	Qual Device: <u>THS4130DGK</u>	QBS Product Reference: <u>THS4130ID</u>	QBS Process Reference: <u>OPA2810IDGK</u>	QBS Package Reference: <u>OPA2607QDGKRQ1</u>	QBS Package Reference: <u>OPA2991QDGKRQ1</u>
LI	Lead Pull to Destruction	Leads	-	-	-	-	1/24/0
PD	Auto Physical Dimensions	Cpk>1.67	-	-	-	3/30/0	-
SD	Surface Mount Solderability	Pb	-	-	-	1/15/0	1/15/0
SD	Surface Mount Solderability	Pb Free	-	-	-	1/15/0	1/15/0
UHAST	Unbiased HAST 130C/85%RH	96 Hours	1/77/0	-	3/231/0	1/77/0	-

- Preconditioning was performed for Autoclave, Unbiased HAST, THB/Biased HAST, Temperature Cycle, Thermal Shock, and HTSL, as applicable

- The following are equivalent HTOL options based on an activation energy of 0.7eV: 125C/1k Hours, 140C/480 Hours, 150C/300 Hours, and 155C/240 Hours

The following are equivalent HTSL options based on an activation energy of 0.7eV: 150C/1k Hours, and 170C/420 Hours
The following are equivalent Temp Cycle options per JESD47: -55C/125C/700 Cycles and -65C/150C/500 Cycles

Quality and Environmental data is available at TI's external Web site: http://www.ti.com/ Green/Pb-free Status:

Qualified Pb-Free (SMT) and Green

Note (1): Two units failed Vio due to bad BI socket contact

Texas Instruments Incorporated

Qualification Report

Approve Date 11-May-2022

Qualification Results Data Displayed as: Number of lots / Total sample size / Total failed

	Туре	Test Name / Condition	Duration	Qual Device: <u>THS4131DGK</u>	QBS Product Reference: <u>THS4130DGK</u>	QBS Product Reference: <u>THS4130ID</u>	QBS Process Reference: <u>OPA2810IDGK</u>	QBS Package Reference: <u>OPA2607QDGKRQ1</u>	QBS Package Reference: <u>OPA2991QDGKRQ1</u>
1	HTOL	Life Test, 125C	1000 Hours	-	-	-	3/231/0	-	-
1	HTOL	Life Test, 150C	408 Hours	-	-	-	-	1/77/0	3/231/1 (1)
1	ELFR	Early Life Failure Rate, 125C	48 Hours	-	-	-	3/3000/0	-	-
	нвм	ESD - HBM	2500 V	-	-	1/3/0	3/9/0	1/3/0	-
	CDM	ESD - CDM	1500 V	-	1/3/0	1/3/0	2/6/0	1/3/0	-
	LU	Latch-up	Per JESD78	-	-	1/6/0	3/18/0	-	-
	ED	Electrical Characterization	Per Datasheet Parameters	-	-	1/30/0	3/90/0	-	-
U	IHAST	Unbiased HAST 130C/85%RH	96 Hours	-	1/77/0	-	3/231/0	1/77/0	-
	тс	Temperature Cycle, -65/150C	500 Cycles	-	1/77/0	-	3/231/0	-	3/231/0
	AC	Autoclave 121C	96 Hours	-	-	-	-	-	3/231/0
	HAST	Biased HAST, 130C/85%RH	192 hours	-	-	-	-	-	1/70/0
1	HAST	Biased HAST, 130C/85%RH	96 Hours	-	-	-	3/231/0	1/77/0	3/231/2 (1)
	HTSL	High Temp Storage Bake 150C	1000 Hours	-	-	-	-	1/77/0	2/90/0
	HTSL	High Temp Storage Bake 170C	420 Hours	-	-	-	3/231/0	-	-
	LI	Lead Pull	Lead Pull	-	-	-	-	1/6/0	-

	Туре	Test Name / Condition	Duration	Qual Device: <u>THS4131DGK</u>	QBS Product Reference: <u>THS4130DGK</u>	QBS Product Reference: <u>THS4130ID</u>	QBS Process Reference: <u>OPA2810IDGK</u>	QBS Package Reference: <u>OPA2607QDGKRQ1</u>	QBS Package Reference: <u>OPA2991QDGKRQ1</u>
	Ц	Lead Pull to	Leads	-	-	-	-	-	1/24/0
		Destruction							
	PD	Auto Physical	Cpk>1.67	-	-	-	-	3/30/0	-
		Dimensions							
	SD	Surface Mount	Pb	-	-	-	-	1/15/0	1/15/0
		Solderability							
	SD	Surface Mount	Pb Free	-	-	-	-	1/15/0	1/15/0
		Solderability							
	YLD	FTY and Bin Summary	-	1/Pass	-	-	-	-	-

- Preconditioning was performed for Autoclave, Unbiased HAST, THB/Biased HAST, Temperature Cycle, Thermal Shock, and HTSL, as applicable

The following are equivalent HTOL options based on an activation energy of 0.7eV: 125C/1k Hours, 140C/480 Hours, 150C/300 Hours, and 155C/240 Hours

The following are equivalent HTSL options based on an activation energy of 0.7eV: 150C/1k Hours, and 170C/420 Hours
The following are equivalent Temp Cycle options per JESD47: -55C/125C/700 Cycles and -65C/150C/500 Cycles

Quality and Environmental data is available at TI's external Web site: http://www.ti.com/ Green/Pb-free Status:

Note (1): Two units failed Vio due to bad BI socket contact

For questions regarding this notice, e-mails can be sent to the contact below or your local Field Sales Representative.

Location	E-Mail				
WW Change Management Team	PCN ww admin team@list.ti.com				

IMPORTANT NOTICE AND DISCLAIMER

TI PROVIDES TECHNICAL AND RELIABILITY DATA (INCLUDING DATASHEETS), DESIGN RESOURCES (INCLUDING REFERENCE DESIGNS), APPLICATION OR OTHER DESIGN ADVICE, WEB TOOLS, SAFETY INFORMATION, AND OTHER RESOURCES "AS IS" AND WITH ALL FAULTS, AND DISCLAIMS ALL WARRANTIES, EXPRESS AND IMPLIED, INCLUDING WITHOUT LIMITATION ANY IMPLIED WARRANTIES OF MERCHANTABILITY, FITNESS FOR A PARTICULAR PURPOSE OR NON-INFRINGEMENT OF THIRD PARTY INTELLECTUAL PROPERTY RIGHTS.

These resources are intended for skilled developers designing with TI products. You are solely responsible for (1) selecting the appropriate TI products for your application, (2) designing, validating and testing your

Qualified Pb-Free (SMT) and Green

application, and (3) ensuring your application meets applicable standards, and any other safety, security, or other requirements. These resources are subject to change without notice. TI grants you permission to use these resources only for development of an application that uses the TI products described in the resource. Other reproduction and display of these resources is prohibited. No license is granted to any other TI intellectual property right or to any third party intellectual property right. TI disclaims responsibility for, and you will fully indemnify TI and its representatives against, any claims, damages, costs, losses, and liabilities arising out of your use of these resources.

TI's products are provided subject to TI's Terms of Sale (<u>www.ti.com/legal/termsofsale.html</u>) or other applicable terms available either on ti.com or provided in conjunction with such TI products. TI's provision of these resources does not expand or otherwise alter TI's applicable warranties or warranty disclaimers for TI products.